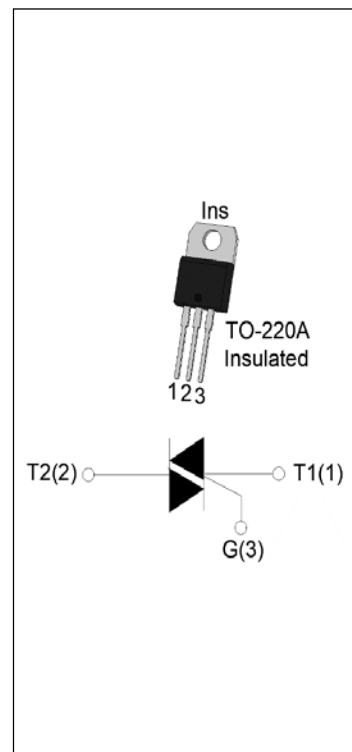


JST16i-800CW 16A TRIAC

Rev.A.1.1

DESCRIPTION:

The JST16i-800CW triac is suitable for general purpose AC switching. It is more suitable for the switch functions of washing machines' water valve, positive inversion of motor, heat pump... JST16i-800CW snubberless triac is especially recommended for use on inductive loads. By using an internal ceramic pad, JST16i-800CW provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.


MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
V_{DRM}/V_{RRM}	800	V
$I_{GT\ I/II/III}$	35/35/35	mA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	°C
Operating junction temperature range	T_j	-40-125	°C
Repetitive peak off-state voltage ($T_j=25^\circ\text{C}$)	V_{DRM}	800	V
Repetitive peak reverse voltage ($T_j=25^\circ\text{C}$)	V_{RRM}	800	V
RMS on-state current ($T_c \leq 81^\circ\text{C}$)	$I_{T(RMS)}$	16	A
Non repetitive surge peak on-state current (full cycle , $t_p=20\text{ms}$, $T_j=25^\circ\text{C}$)	I_{TSM}	170	A
Non repetitive surge peak on-state current (full cycle , $t_p=16.6\text{ms}$, $T_j=25^\circ\text{C}$)		180	
I^2t value for fusing ($t_p=10\text{ms}$, $T_j=25^\circ\text{C}$)	I^2t	145	A^2s
Critical rate of rise of on-state current ($I_G=2 \times I_{GT}$, $f=100\text{Hz}$, $T_j=125^\circ\text{C}$)	di/dt	100	$\text{A}/\mu\text{s}$
Peak gate current ($t_p=20\mu\text{s}$, $T_j=125^\circ\text{C}$)	I_{GM}	4	A
Average gate power dissipation ($T_j=125^\circ\text{C}$)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	10	W

Peak pulse voltage ($T_j=25^{\circ}\text{C}$; non-repetitive, off-state; FIG.7)	V_{pp}	4	kV
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ELECTRICAL CHARACTERISTICS ($T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12\text{V}$ $R_L=33\Omega$	I - II -III	MAX.	35	mA
V_{GT}		I - II -III	MAX.	1	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125^{\circ}\text{C}$ $R_L=3.3\text{k}\Omega$	I - II -III	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	I -III	MAX.	50	mA
		II		60	
I_H	$I_T=500\text{mA}$		MAX.	40	mA
dV/dt	$V_D=540\text{V}$ Gate Open $T_j=125^{\circ}\text{C}$		MIN.	1200	V/ μs
$(dI/dt)_c$	$(dV/dt)_c=20\text{V}/\mu\text{s}$ $T_j=125^{\circ}\text{C}$		MIN.	12	A/ms
t_{on}	$I_G=40\text{mA}$ $I_A=200\text{mA}$ $I_R=20\text{mA}$ $T_j=25^{\circ}\text{C}$		TYP.	5	μs
t_{off}				50	

STATIC CHARACTERISTICS

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_{TM}=22.5\text{A}$ $t_p=380\mu\text{s}$	$T_j=25^{\circ}\text{C}$	1.45	V
V_{TO}	Threshold voltage	$T_j=125^{\circ}\text{C}$	0.75	V
R_D	Dynamic resistance	$T_j=125^{\circ}\text{C}$	32	$\text{m}\Omega$
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25^{\circ}\text{C}$	5	μA
I_{RRM}		$T_j=125^{\circ}\text{C}$	0.5	mA

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	junction to case (AC)	2	$^{\circ}\text{C}/\text{W}$
$R_{th(j-a)}$	junction to ambient (AC)	60	$^{\circ}\text{C}/\text{W}$

ORDERING INFORMATION

<u>J</u>	<u>ST</u>	<u>16</u>	<u>i</u>	<u>-800</u>	<u>CW</u>
JieJie Microelectronics Co., Ltd.	Triacs	$I_T(RMS):16A$	$i:TO-220A(Ins)$	$800:V_{DRM}/V_{RRM} \geq 800V$	$CW:I_{GT1-3} \leq 35mA$

MARKING

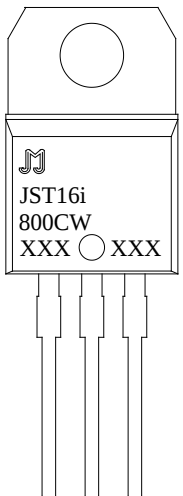
	<u>XXX</u> <u>XXX</u> Year ———— Month ———— Production Code
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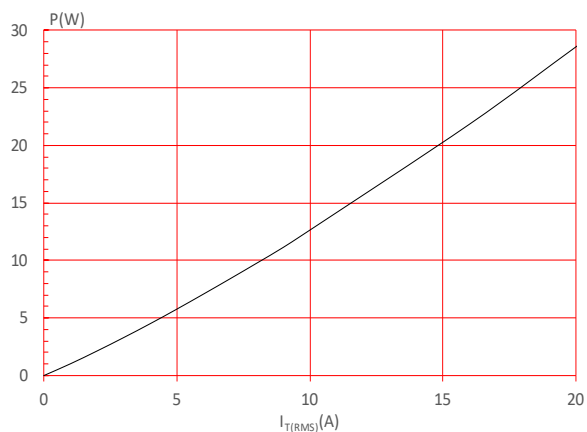
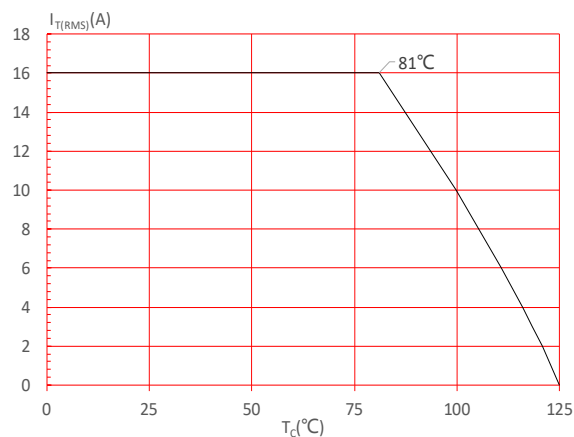
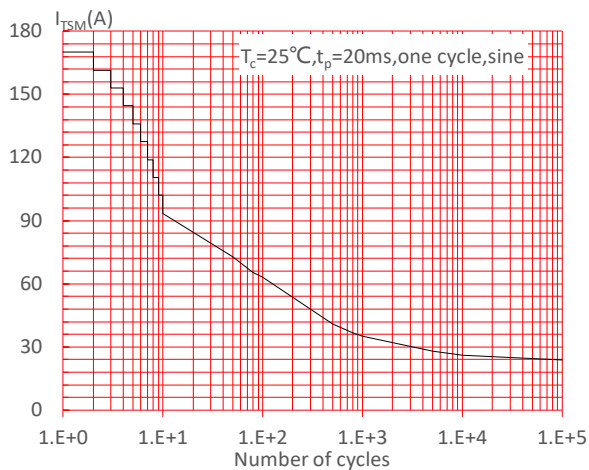
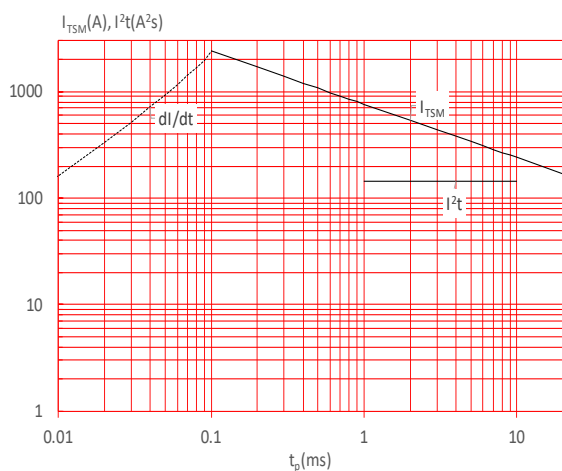
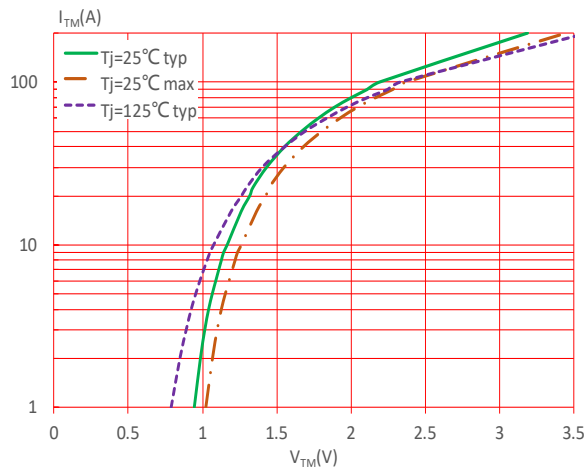
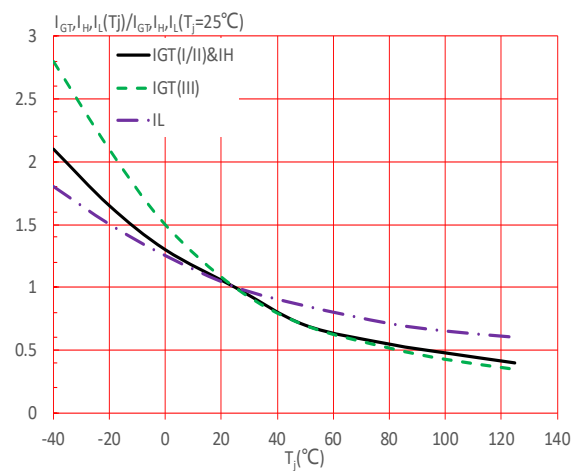
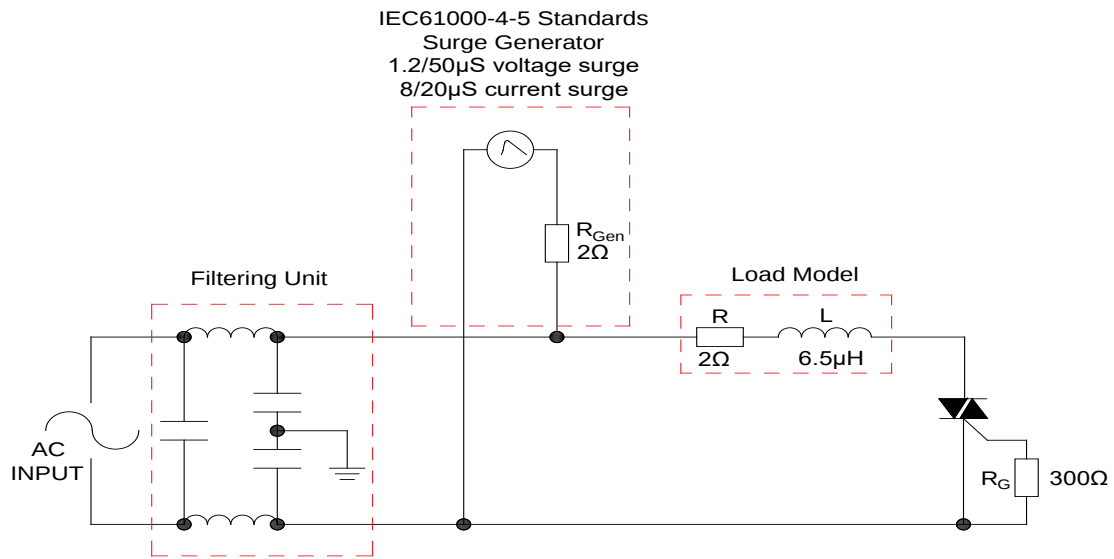
FIG.1: Maximum power dissipation versus RMS on-state current**FIG.2:** RMS on-state current versus case temperature**FIG.3:** Surge peak on-state current versus number of cycles**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$, and corresponding value of I^2t ($di/dt < 100A/\mu s$)**FIG.4:** On-state characteristics**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

FIG.7: Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



LEAD FORMING AND SOLDERING

Refer to the application note “Assembly Instructions for Thyristors in Through-hole Package” released by JieJie Microelectronics

ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		I - II - III			
JST16i-800CW	800	35	TO-220A(Ins)	50	Tube

Document Revision History

Date	Revision	Changes
Apr.10, 2023	A.1.0	Last updated
Oct.14, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

Technical drawing of a 3-pin plug. The drawing includes a top view, a front view, and a side view. Dimensions are labeled as follows:

- A**: Total height of the plug.
- B**: Height of the base.
- C**: Diameter of the base.
- D**: Height of the main body.
- E**: Total width of the plug.
- F**: Width of the top flange.
- G**: Width of the base.
- H**: Total height of the plug (same as A).
- I**: Width of the top flange (same as F).
- J**: Height of the main body (same as D).
- K**: Width of the base (same as G).
- L1**: Height of the top flange.
- L2**: Height of the main body (same as D).
- L3**: Height of the base (same as B).

A note indicates a hole diameter of $\Phi 3.7-3.9\text{mm}$.

Technical drawing of a 3D printed part, showing three views: top, front, and side views. The dimensions are as follows:

- Top View:**
 - Overall width: 520 ± 0.5
 - Overall height: 530 ± 0.5
 - Distance from left edge to center of hole: 80
 - Radius of hole: $\phi 4.5$
 - Distance from center of hole to right edge: 5
 - Distance from top edge to center of hole: 3
 - Label: "printing area"
- Front View:**
 - Overall width: 530 ± 0.5
 - Overall height: 5.5
 - Radius of hole: $\phi 3.0 \pm 0.05$
- Side View:**
 - Overall width: $7.0_{-0.2}^0$
 - Overall height: 33
 - Distance from top edge to center of hole: 3.8
 - Distance from center of hole to bottom edge: 0.6
 - Distance from left edge to center of hole: 2.4
 - Distance from center of hole to right edge: 3.8

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